TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSV)

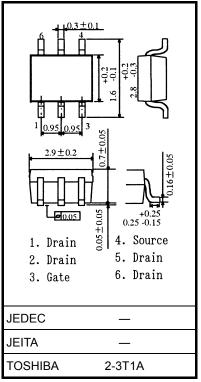
# **TPC6111**

## Notebook PC Applications Portable Equipment Applications

- Low drain-source ON resistance:  $R_{DS}$  (ON) = 33 m $\Omega$  (typ.)
- Low leakage current:  $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -20 \ V)$
- Enhancement mode:  $V_{th} = -0.3$  to -1.0 V
  - $(V_{DS} = -10 \text{ V}, I_D = -1 \text{mA})$

## Absolute Maximum Ratings (Ta = 25°C)

Character	ristics	Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	-20	V
Drain-gate voltage (R	<sub>GS</sub> = 20 kΩ)	V <sub>DGR</sub>	-20	V
Gate-source voltage		V <sub>GSS</sub>	± 8	V
	DC (Note 1)	Ι <sub>D</sub>	-5.5	^
Drain current	Pulse (Note 1)	I <sub>DP</sub>	-22	A
Drain power dissipatio	on (t = 5 s) (Note 2a)	PD	2.2	W
Drain power dissipatio	on (t = 5 s) (Note 2b)	PD	0.7	W
Single pulse avalanch	e energy (Note 3)	E <sub>AS</sub>	5.1	mJ
Avalanche current		I <sub>AR</sub>	-2.8	А
Repetitive avalanche	energy (Note 4)	E <sub>AR</sub>	0.019	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature	range	T <sub>stg</sub>	-55~150	°C



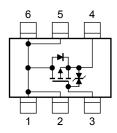
Weight: 0.011 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 5 s)$ (Note 2a)	R <sub>th (ch-a)</sub>	56.8	°C/W
Thermal resistance, channel to ambient (t = 5 s) (Note 2b) $% = 10^{-10}$	R <sub>th (ch-a)</sub>	178.5	°C/W

### **Circuit Configuration**



Note: (Note 1), (Note 2), (Note 3), (Note 4) and (Note 5): See other pages.

This transistor is an electrostatic-sensitive device. Please handle with caution.

Unit: mm

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**Electrical Characteristics (Ta = 25°C)** 

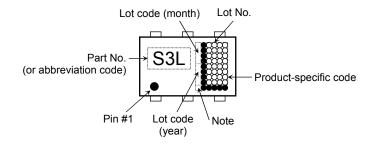
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μA	
Drain cut-off currer	Drain cut-off current		$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	-10	μA	
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ -20		_		V	
		V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 8 \text{ V}$	-12		_	v	
Gate threshold volt	tage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, \text{ I}_D = -1\text{mA}$	-0.3		-1.0	V	
Drain-source ON resistance		R <sub>DS (ON)</sub>	$V_{GS} = -1.5 \text{ V}, \text{ I}_{D} = -1.4 \text{ A}$		76	150		
		R <sub>DS (ON)</sub>	$V_{GS} = -1.8 \text{ V}, I_D = -1.4 \text{ A}$		56	80	<b>m</b> 0	
Drain-source ON I	esistance	R <sub>DS (ON)</sub>	$V_{GS} = -2.5 \text{ V}, \text{ I}_D = -2.8 \text{ A}$		44	57	mΩ	
		R <sub>DS (ON)</sub>	$V_{GS} = -4.5 \text{ V}, \text{ I}_D = -2.8 \text{ A}$		33	40		
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -2.8 \text{ A}$	7	14		S	
Input capacitance		C <sub>iss</sub>			700		pF	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = -10 \text{ V},  V_{GS} = 0 \text{ V},  \text{f} = 1  \text{MHz}$	_	100	_		
Output capacitance		C <sub>oss</sub>		_	140	_		
	Rise time	tr	$V_{GS} \xrightarrow{0 V} I_{D} = -2.8 \text{ A}$		7		ns	
Switching time	Turn-on time	t <sub>on</sub>			12	_		
	Fall time	t <sub>f</sub>	RL = 3.6 5		30	_		
	Turn-off time	t <sub>off</sub>	$V_{DD}\approx -10~V$ Duty $\leq$ 1%, $t_W=10~\mu s$		95			
Total gate charge (gate-source plus gate-drain)		Qg	V <sub>DD</sub> ≈ −16 V, V <sub>GS</sub> = −5 V,	_	10	_	nC	
Gate-source charge 1		Q <sub>gs 1</sub>	$I_{\rm D} = -5.5 \rm{A}$	_	1.2			
Gate-drain ("miller") charge		Q <sub>gd</sub>			2.5			

### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics Symbol		Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	I <sub>DRP</sub>	—	_	_	-22	А
Forward voltage	rward voltage (diode) V <sub>DSF</sub>		$I_{DR} = -5.5 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$		-	1.2	V

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# Marking (Note 5)



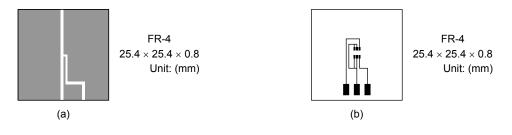
Note: A dot marking for identifying the indication of product Labels. Without a dot: [[Pb]]/INCLUDES > MCV With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

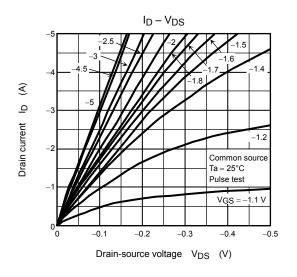
The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

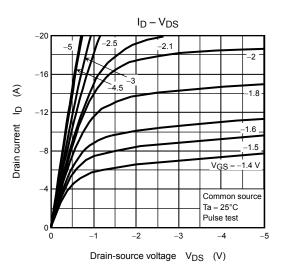
Note 1: Ensure that the channel temperature does not exceed 150°C.

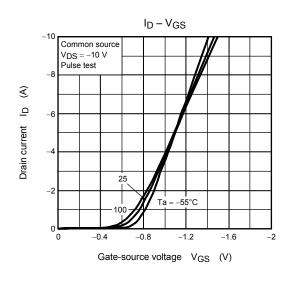
Note 2: (a) Device mounted on a glass-epoxy board (a) (t = 5 s) (b) Device mounted on a glass-epoxy board (b) (t = 5 s)

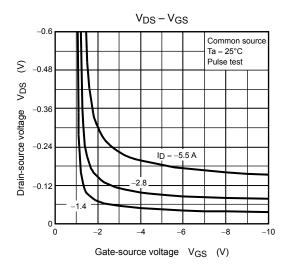


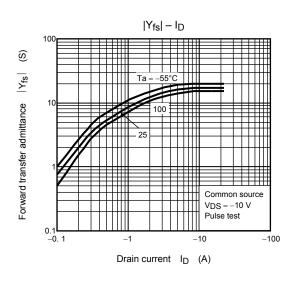
- Note 3:  $V_{DD} = -16 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$  (initial), L = 0.5 mH, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = -2.8 A
- Note 4: Repetitive rating;:pulse width limited by maximum channel temperature
- Note 5: on lower left of the marking indicates Pin 1.

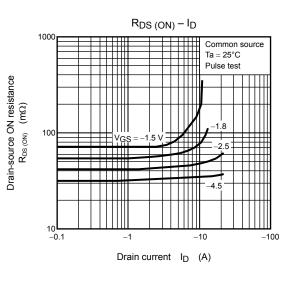




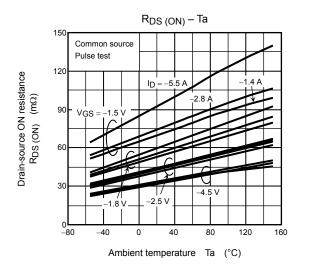


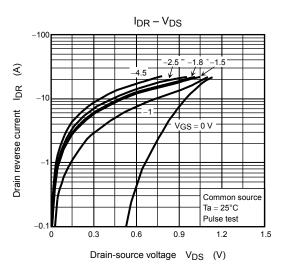


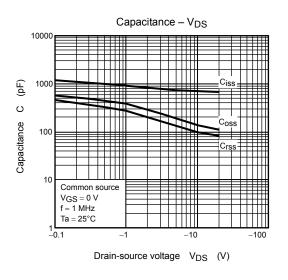


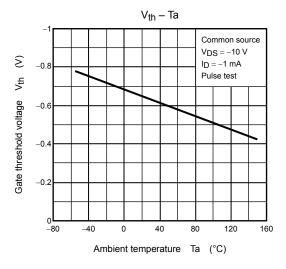


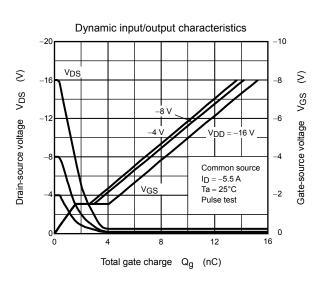
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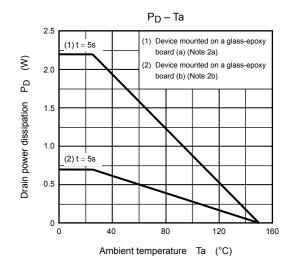




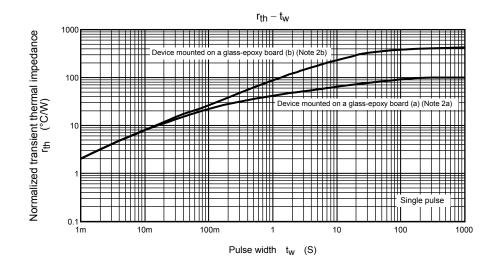


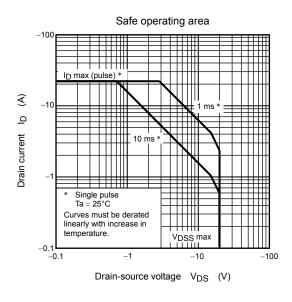












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